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Features

- Up to 107MHz operation
- Capacitors 8pF CG and 16pF CD built-in
- Inverter amplifier feedback resistor built-in
- TTL input level
- 16 mA (VDD = 4.5 V) drive capability
- 4 mA (VDD = 4.5 V) drive capability (PT7C5006AHx)
- Output three-state function
- 2.7 to 5.5 V supply voltage
- Oscillator frequency output
- 8-pin SOIC package (PT7C5006xxxW) and Die form (PT7C5006xxxDE) available

Application

- Used for crystal oscillator

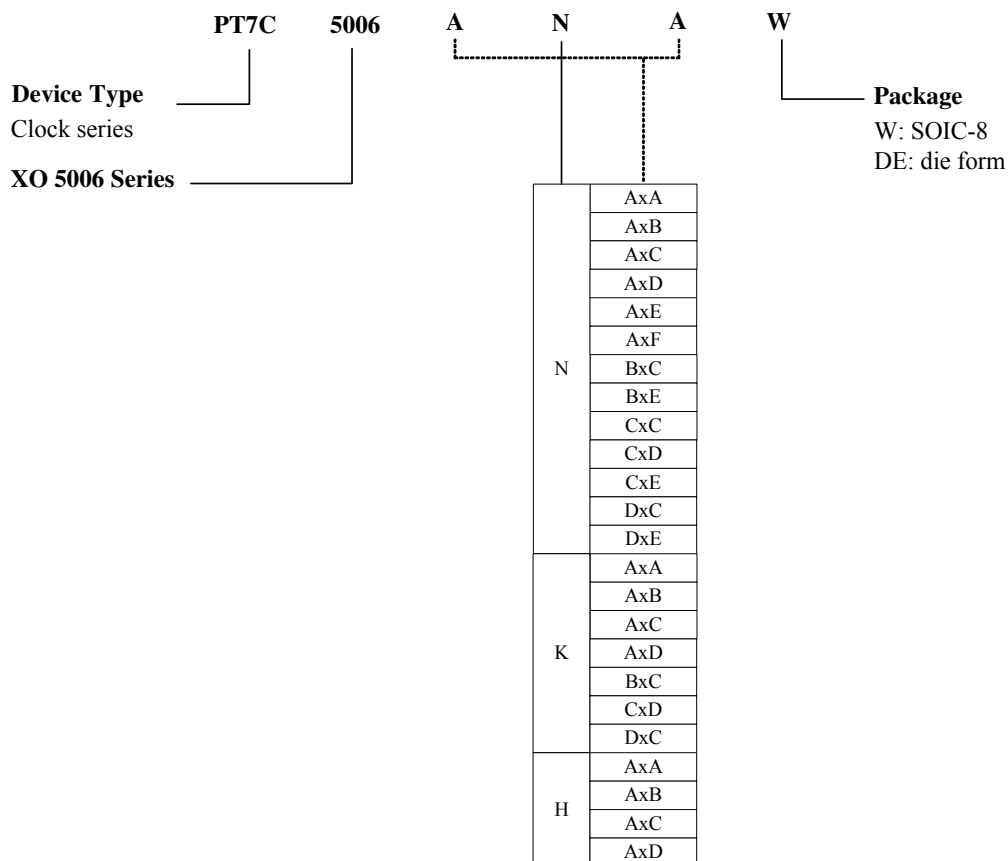
Description

The PT7C5006 series are crystal oscillator module ICs, that incorporate high-frequency, low current consumption oscillator and output buffer circuits. Highly accurate feedback resistors and high-frequency capacitors are built-in, eliminating the need for external components to make a stable 3rd-harmonic oscillator.

Ordering Information

Part no.	Package type
PT7C5006xxxW	SOIC-8
PT7C5006xxxWE	Lead free SOIC-8
PT7C5006xxxDE	DIE

Note : Below is the detailed definition of part no.



Series Configuration

Part No.	g _m ratio	R _f (kΩ)	3V operating		5V operating			Built-in capacitance		Input level	Output Duty level
			Output load (max) (pF)	Recommended Operating Frequency Rang (MHz)	Output load (max) (pF)	Recommended Operating Frequency Rang (MHz)	Output Waveform ²⁾ t _r /t _f (ns)	C _G (pF)	C _D (pF)		
PT7C5006ANA	0.5	8.2	-	-	50	22 to 30	8/8	8	16	TTL	CMOS
PT7C5006ANB	1	5.6	-	-	50	30 to 40	8/8				
PT7C5006ANC	2	4.9	15	22 to 30	50	40 to 60	7/7				
PT7C5006AND	2	2.6	15	30 to 50	50	50 to 70	7/7				
PT7C5006ANE	3	2.6	15	50 to 70	30 15 ¹⁾	70 to 100	6/6				
PT7C5006ANF	4	2.6	-	-	30 15 ¹⁾	80 to 107	6/6				
PT7C5006CNC	2	4.9	15	22 to 30	15 50	40 to 60 40 to 50	8/8				
PT7C5006CND	2	2.6	15	30 to 40	15	50 to 70	8/8				
PT7C5006CNE	3	2.6	15	50 to 70	15	70 to 100	7/7				
PT7C5006BNC	2	No	15	22 to 70	15 50	22 to 100 22 to 70	7/7				
PT7C5006BNE	3	No	15	22 to 70	30 15 ¹⁾	70 to 107	6/6				
PT7C5006DNC	2	No	15	22 to 40	15 50	22 to 70 22 to 50	8/8				
PT7C5006DNE	3	No	15	22 to 70	15 50	22 to 100 22 to 70	7/7				
PT7C5006AKA	0.5	8.2	-	-	15	22 to 30	4/4	8	16	TTL	TTL
PT7C5006AKB	1	5.6	-	-	15	30 to 40					
PT7C5006AKC	2	4.9	-	-	15	40 to 60					
PT7C5006AKD	2	2.6	-	-	15	50 to 70					
PT7C5006CKD	2	2.6	-	-	15	50 to 70					
PT7C5006BKC	2	No	-	-	15	22 to 70					
PT7C5006DKC	2	No	-	-	15	22 to 70	7/7	8	16	TTL	CMOS
PT7C5006AHA	0.5	8.2	-	-	15	22 to 30					
PT7C5006AHB	1	5.6	-	-	15	30 to 40					
PT7C5006AHC	2	4.9	-	-	15	40 to 60					
PT7C5006AHD	2	2.6	-	-	15	50 to 70					

1): SOIC package only.

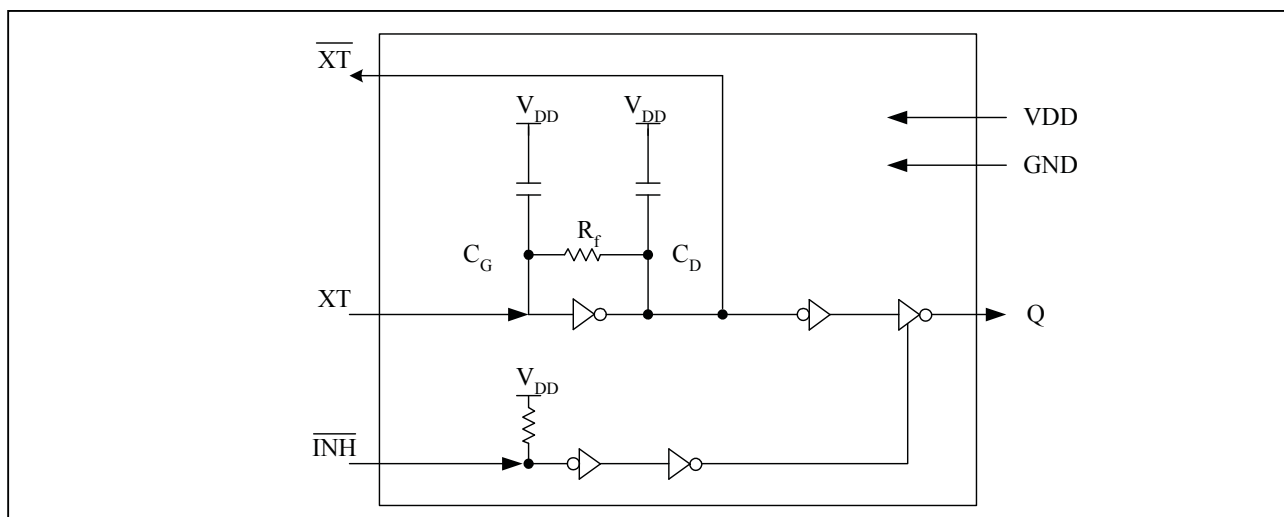
2): 5006xNx: C_L= 50pF, CMOS load

5006xKx: C_L= 15pF, 10TTL load

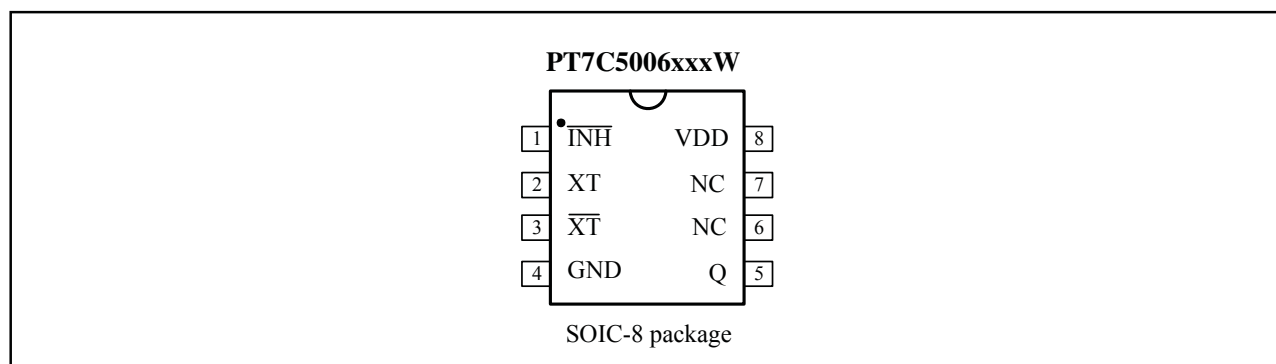
5006AHx: C_L= 15pF, CMOS load

Note: Recommend operating frequency is not the guaranteed value but is measured using PTI's standard crystal.

Block Diagram



Pin Configuration



Pin Description

Pin	Sym.	Type	Description
1	$\overline{INH}$	I	Output state control input. High impedance when LOW. Pull-up resistor built in.
2	XT	I	Amplifier input.
3	$\overline{XT}$	O	Amplifier output.
Crystal oscillator connected between XT and $\overline{XT}$			
4	GND	P	Ground
5	Q	O	Output. Output frequency (f_o).
6,7	NC	-	No connection
8	V_{DD}	P	Supply voltage

Function Description

When $\overline{\text{INH}}$ goes LOW, the output on Q becomes high impedance, but internally the oscillator does not stop.

$\overline{\text{INH}}$	Oscillator	Q
High (or open)	Normal operation	Output f_o frequency
Low	Normal operation	High impedance

Maximum Ratings

Storage Temperature (die form)	-65°C to +150°C
Storage Temperature (package form)	-40°C to +125°C
Ambient Temperature with Power Applied	-40°C to +85°C
Supply Voltage to Ground Potential (V_{DD} to GND)	-0.5V to 7.0V
Input Voltage (All Inputs except V_{DD} & GND)	-0.5V to $V_{DD} + 0.5V$
Output Voltage	-0.5V to $V_{DD} + 0.5V$
Output Current (PT7C5006xNx/xKx)	25mA
Output Current (PT7C5006AHx)	10mA
Power Dissipation	200mW (package form)

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

PT7C5006 series (package form)

Sym.	Parameter	Series	Conditions	Min	Typ	Max	Unit
V _{DD}	Supply voltage	ANA, ANB, CNC, CND, DNC	f ≤ 50MHz, C _L =50pF	4.5	-	5.5	V
			f ≤ 70MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 40MHz, C _L =15pF	2.7	-	3.6	
		ANC, AND, BNC, CNE, DNE	f ≤ 70MHz, C _L =50pF	4.5	-	5.5	V
			f ≤ 100MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 50MHz, C _L =15pF	2.7	-	3.6	
		ANE, ANF, BNE	f ≤ 70MHz, C _L =15pF	3.0	-	3.6	V
			f ≤ 100MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 107MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 50MHz, C _L =15pF	2.7	-	3.6	
		AKA, AKB, AKC, CKD,DKC	f ≤ 70MHz, C _L =15pF	4.5	-	5.5	V
			f ≤ 70MHz, C _L =15pF	4.5	-	5.5	
V _{IN}	Input voltage	All series		GND	-	V _{DD}	V
T _{OPR}	Operating temperature	ANA, ANB, CNC, CND, DNC	f ≤ 50MHz, C _L =50pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	80	°C
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	0	-	70	
			f ≤ 40MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-10	-	70	
		ANC, AND, BNC, CNE, DNE	f ≤ 50MHz, C _L =50pF, 2.7 ≤ V _{DD} ≤ 5.5	-40	-	80	°C
			f ≤ 70MHz, C _L =50pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	
			f ≤ 100MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	0	-	70	
			f ≤ 50MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-20	-	80	
			f ≤ 70MHz, C _L =15pF, 3.0 ≤ V _{DD} ≤ 3.6	-20	-	80	
		ANE, ANF, BNE	f ≤ 70MHz, C _L =50pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	°C
			f ≤ 100MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	
			f ≤ 107MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	
			f ≤ 50MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-20	-	80	
			f ≤ 70MHz, C _L =15pF, 3.0 ≤ V _{DD} ≤ 3.6	-20	-	80	
		AKA, AKB, AKC, CKD, DKC	f ≤ 50MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	°C
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	0	-	70	
		AKD, BKC	f ≤ 50MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	°C
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	
		AHA, AHB, AHC, AHD	f ≤ 50MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	°C
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-15	-	75	

PT7C5006 series (die form)

Sym.	Parameter	Series	Condition	Min	Typ	Max	Unit
V _{DD}	Supply voltage	ANA, ANB, CNC, CND, DNC	f ≤ 50MHz, C _L =50pF	4.5	-	5.5	V
			f ≤ 70MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 40MHz, C _L =15pF	2.7	-	3.6	
		ANC, AND, BNC, CNE, DNE	f ≤ 70MHz, C _L =50pF	4.5	-	5.5	V
			f ≤ 100MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 50MHz, C _L =15pF	2.7	-	3.6	
		ANE, ANF, BNE	f ≤ 70MHz, C _L =15pF	3.0	-	3.6	V
			f ≤ 100MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 10 7MHz, C _L =15pF	4.5	-	5.5	
			f ≤ 50MHz, C _L =15pF	2.7	-	3.6	
		AKA, AKB, AKC, CKD,DKC	f ≤ 70MHz, C _L =15pF	4.5	-	5.5	V
			f ≤ 70MHz, C _L =15pF	4.5	-	5.5	V
		AHA, AHB, AHC, AHD	f ≤ 70MHz, C _L =15pF	4.5	-	5.5	V
V _{IN}	Input voltage	All series		GND	-	V _{DD}	V
T _{OPR}	Operating temperature	ANA, ANB, CNC, CND, DNC	f ≤ 50MHz, C _L =50pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	80	°C
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-15	-	75	
			f ≤ 40MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-10	-	70	
		ANC, AND, BNC, CNE, DNE	f ≤ 70MHz, C _L =50pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	°C
			f ≤ 100MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	
			f ≤ 50MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-20	-	80	
		ANE, ANF, BNE	f ≤ 70MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-20	-	80	°C
			f ≤ 70MHz, C _L =50pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	
			f ≤ 100MHz, C _L =30pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	
			f ≤ 107MHz, C _L =30pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	
		AKA, AKB, AKC, CKD, DKC	f ≤ 50MHz, C _L =15pF, 2.7 ≤ V _{DD} ≤ 3.6	-20	-	80	°C
			f ≤ 70MHz, C _L =15pF, 3.0 ≤ V _{DD} ≤ 3.6	-20	-	80	
		AKD, BKC	f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	°C
			f ≤ 50MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-15	-	75	
		AHA, AHB, AHC, AHD	f ≤ 50MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-40	-	85	°C
			f ≤ 70MHz, C _L =15pF, 4.5 ≤ V _{DD} ≤ 5.5	-20	-	80	

DC Electrical Characteristics

PT7C5006xN series

3V operation: $V_{DD} = 2.7$ to $3.6V$, $T_A = -20$ to $80^\circ C$ unless otherwise noted.

Sym.	Parameter	Condition		Min	Typ	Max	Unit
I_{DD}	Current consumption	$\overline{INH}$ =open, Measurement cct 3, Load cct 1, $V_{DD}=3.0$ to $3.6V$, $C_L=15pF$	$f=30MHz$ PT7C5006ANC PT7C5006BNC	-	8	16	mA
			$f=30MHz$, $T_A = -10$ to $70^\circ C$ PT7C5006CNC	-	8	16	
			$f=50MHz$ PT7C5006AND	-	13	26	
			$f=70MHz$ PT7C5006BNE PT7C5006CNE PT7C5006DNE	-	15	30	
			$f=40MHz$, $T_A = -10$ to $70^\circ C$ PT7C5006CND PT7C5006DNC	-	11	22	
			$f=70MHz$ PT7C5006ANE PT7C5006ANF	-	20	40	
V_{IH}	High-level input voltage	$\overline{INH}$		2.0	-	-	V
V_{IL}	Low-level input voltage	$\overline{INH}$		-	-	0.5	V
R_{up}	$\overline{INH}$ pull-up resistance	Measurement cct 4		50	-	150	k Ω
R_f	Feedback resistance	Measurement cct 5	PT7C5006ANA	6.97	8.2	9.43	k Ω
			PT7C5006ANB	4.76	5.6	6.44	
			PT7C5006ANC, PT7C5006CNC	4.16	4.9	5.64	
			PT7C5006AND, PT7C5006ANE, PT7C5006ANF, PT7C5006CND, PT7C5006CNE	2.21	2.6	2.99	
C_G	Built-in capacitance	Design value, determined by the value internal pattern		7.44	8	8.56	pF
C_D		Design value, determined by the value internal pattern		14.88	16	17.12	
V_{OH}	High-level output voltage	Q: Measurement cct 1, $V_{DD}=2.7V$, $I_{OH}=8mA$		2.2	2.4	-	V
V_{OL}	Low-level output voltage	Q: Measurement cct 2, $V_{DD}=2.7V$, $I_{OL}=8mA$		-	0.3	0.4	V
I_Z	Output leakage current	Q: Measurement cct 2, $\overline{INH}=LOW$, $V_{DD}=5.5V$	$V_{OH} = V_{DD}$	-	-	10	μA
			$V_{OL} = GND$	-	-	10	

PT7C5006xN series

5V operation: V_{DD} = 4.5 to 5.5V, T_A = -40 to 85°C unless otherwise noted.

Sym.	Parameter	Condition			Min	Typ	Max	Unit
I_{DD}	Current consumption	$\overline{INH}$ = open, Measurement cct 3, Load cct 1, V_{DD} = 4.5 to 5.5V, C_L = 50pF	f = 30MHz	PT7C5006ANA	-	18	35	mA
			f = 40MHz,	PT7C5006ANB	-	20	40	
			f = 60MHz	PT7C5006ANCDE	-	30	60	
			f = 60MHz, T_A = -20 to 80°C	PT7C5006ANCW	-	30	50	
			f = 70MHz	PT7C5006ANDDE PT7C5006BNCDE	-	40	80	
			f = 70MHz, T_A = -20 to 80°C	PT7C5006ANDW PT7C5006BNCW	-	40	70	
		$\overline{INH}$ = open, Measurement cct 3, Load cct 1, V_{DD} = 4.5 to 5.5V	f = 60MHz, C_L = 15pF T_A = -15 to 75°C	PT7C5006CNCDE	-	28	50	
			f = 60MHz, C_L = 15pF T_A = 0 to 70°C	PT7C5006CNCW	-	28	50	
			f = 70MHz, C_L = 15pF T_A = -15 to 75°C	PT7C5006CNDDE PT7C5006DNCDE	-	35	65	
			f = 70MHz, C_L = 15pF T_A = 0 to 70°C	PT7C5006CNDW PT7C5006DNCW	-	35	65	
			f = 100MHz, C_L = 15pF T_A = -20 to 80°C	PT7C5006CNEDE PT7C5006DNEDE	-	45	80	
			f = 100MHz, C_L = 15pF T_A = 0 to 70°C	PT7C5006CNEW PT7C5006DNEW	-	45	80	
			f = 100MHz, C_L = 30pF	PT7C5006ANEDE	-	50	100	
			f = 100MHz, C_L = 15pF	PT7C5006ANEW	-	45	90	
			f = 107MHz, C_L = 30pF T_A = -20 to 80°C	PT7C5006ANFDE PT7C5006BNEDE	-	60	100	
			f = 107MHz, C_L = 15pF T_A = -20 to 80°C	PT7C5006ANFW PT7C5006BNEW	-	50	90	
V_{IH}	High-level input voltage	$\overline{INH}$			2.0	-	-	V
V_{IL}	Low-level input voltage	$\overline{INH}$			-	-	0.8	V
R_{up}	$\overline{INH}$ pull-up resistance	Measurement cct 4			50	-	150	k Ω
R_f	Feedback resistance	Measurement cct 5	PT7C5006ANA		6.97	8.2	9.43	k Ω
			PT7C5006ANB		4.76	5.6	6.44	
			PT7C5006ANC, PT7C5006CNC		4.16	4.9	5.64	
			PT7C5006AND, PT7C5006ANES, PT7C5006ANF, PT7C5006CND, PT7C5006CNE		2.21	2.6	2.99	
C_G	Built-in capacitance	Design value, determined by the value internal pattern			7.44	8	8.56	pF
C_D		Design value, determined by the value internal pattern			14.88	16	17.12	
V_{OH}	High-level output voltage	Q: Measurement cct 1, V_{DD} = 4.5V, I_{OH} = 16mA			4.0	4.2	-	V
V_{OL}	Low-level output voltage	Q: Measurement cct 2, V_{DD} = 4.5V, I_{OL} = 16mA			-	0.3	0.4	V
I_Z	Output leakage current	Q: Measurement cct 2, $\overline{INH}$ = LOW, V_{DD} = 5.5V	$V_{OH} = V_{DD}$		-	-	10	μ A
			$V_{OL} = GND$		-	-	10	

PT7C5006×K series

$V_{DD} = 4.5$ to $5.5V$, $T_A = -40$ to $85^{\circ}C$ unless otherwise noted.

Sym.	Parameter	Condition			Min	Typ	Max	Unit
I _{DD}	Current consumption	INH = open, Measurement cct 3, Load cct 1, V _{DD} = 4.5 to 5.5V, C _L = 15pF	f = 30MHz	PT7C5006AKA	-	16	32	mA
			f = 40MHz	PT7C5006AKB	-	18	36	
			f = 60MHz, T _A = -15 to 75°C	PT7C5006AKCDE PT7C5006DKCDE	-	25	50	
			f = 60MHz, T _A = 0 to 70°C	PT7C5006AKCW PT7C5006DKCW	-	25	50	
			f = 70MHz, T _A = -20 to 80°C	PT7C5006AKDDE PT7C5006BKCDE	-	35	70	
			f = 70MHz, T _A = -15 to 75°C	PT7C5006CKDDE	-	35	70	
			f = 70MHz, T _A = 0 to 70°C	PT7C5006AKDW PT7C5006BKCW PT7C5006CKDW	-	35	70	
V _{IH}	High-level input voltage	INH			2.0	-	-	V
V _{IL}	Low-level input voltage	INH			-	-	0.8	V
R _{up}	INH pull-up resistance	Measurement cct 4			50	-	150	kΩ
R _f	Feedback resistance	Measurement cct 5	PT7C5006AKA		6.97	8.2	9.43	kΩ
			PT7C5006AKB		4.76	5.6	6.44	
			PT7C5006AKC		4.16	4.9	5.64	
			PT7C5006AKD, PT7C5006CKD		2.21	2.6	2.99	
C _G	Built-in capacitance	Design value, determined by the value internal pattern			7.44	8	8.56	pF
C _D		Design value, determined by the value internal pattern			14.88	16	17.12	
V _{OH}	High-level output voltage	Q: Measurement cct 1, V _{DD} = 4.5V, I _{OH} = 16mA	PT7C5006AKA, PT7C5006AKB PT7C5006AKC, PT7C5006CKD, PT7C5006DKC		3.9	4.2	-	V
			PT7C5006AKD, PT7C5006BKC		4.0	4.2	-	
V _{OL}	Low-level output voltage	Q: Measurement cct 2, V _{DD} = 4.5V, I _{OL} = 16mA			-	0.3	0.4	V
I _Z	Output leakage current	Q: Measurement cct 2, INH = LOW, V _{DD} = 5.5V	V _{OH} = V _{DD}		-	-	10	μA
			V _{OL} = V _{SS}		-	-	10	

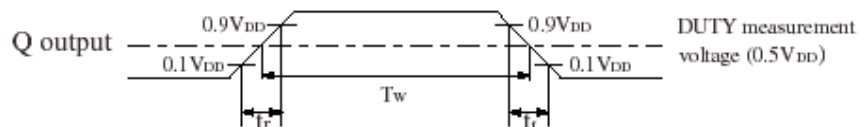
PT7C5006AH series

$V_{DD} = 4.5$ to $5.5V$, $T_A = -40$ to $85^{\circ}C$ unless otherwise noted.

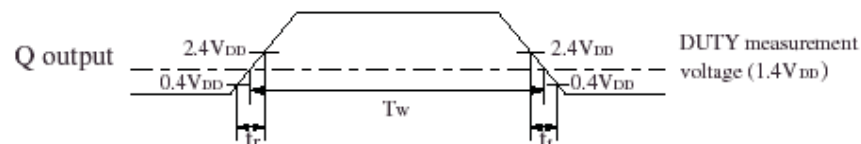
Sym.	Parameter	Condition			Min	Typ	Max	Unit
I _{DD}	Current consumption	$\overline{INH}$ =open, Measurement cct 3, Load cct 1, V _{DD} = 4.5 to 5.5V, C _L = 15pF	f = 30MHz	PT7C5006AHA	-	15	30	mA
			f = 40MHz,	PT7C5006AHB	-	18	36	
			f = 60MHz, T _A = -20 to 80°C	PT7C5006AHCDE	-	25	50	
			f = 60MHz, T _A = -15 to 75°C	PT7C5006AHCW	-	25	50	
			f = 70MHz, T _A = -20 to 80°C	PT7C5006AHDDE	-	32	65	
			f = 70MHz, T _A = -15 to 75°C	PT7C5006AHDW	-	32	65	
V _{IH}	High-level input voltage	$\overline{INH}$			2.0	-	-	V
V _{IL}	Low-level input voltage	$\overline{INH}$			-	-	0.8	V
R _{up}	$\overline{INH}$ pull-up resistance	Measurement cct 4			50	-	150	kΩ
R _f	Feedback resistance	Measurement cct 5	PT7C5006AHA		6.97	8.2	9.43	kΩ
			PT7C5006AHB		4.76	5.6	6.44	
			PT7C5006AHC		4.16	4.9	5.64	
			PT7C5006AHD		2.21	2.6	2.99	
C _G	Built-in capacitance	Design value, determined by the value internal pattern			7.44	8	8.56	pF
C _D		Design value, determined by the value internal pattern			14.88	16	17.12	
V _{OH}	High-level output voltage	Q: Measurement cct 1, V _{DD} = 4.5V, I _{OH} = 4mA			3.9	4.2	-	V
V _{OL}	Low-level output voltage	Q: Measurement cct 2, V _{DD} = 4.5V, I _{OL} = 4mA			-	0.3	0.5	V
I _Z	Output leakage current	Q: Measurement cct 2, $\overline{INH}$ = LOW, V _{DD} =5.5V		V _{OH} = V _{DD}	-	-	10	μA
				V _{OL} = GND	-	-	10	

AC Electrical Characteristics

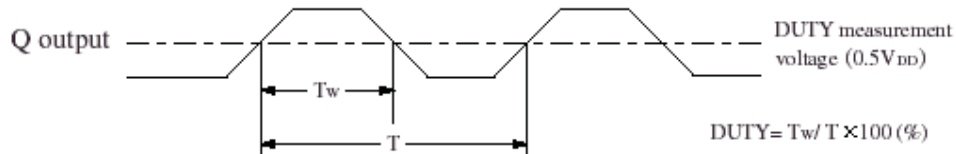
Output duty level (CMOS)



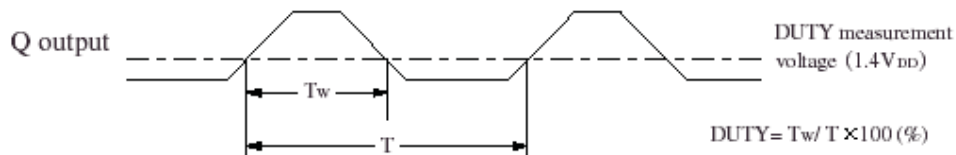
Output duty level (TTL)



Output duty cycle (CMOS)



Output duty cycle (TTL)



PT7C5006xN series

3V operation: $V_{DD} = 2.7$ to $3.6V$, $T_A = -20$ to $80^{\circ}C$, unless otherwise noted.

Sym.	Parameter	Condition			Min	Typ	Max	Unit
t_r	Output rise time	Measurement cct 3, Load cct 1, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 15pF$	$T_A = -10$ to $70^{\circ}C$	PT7C5006ANA, PT7C5006ANB, PT7C5006CNC, PT7C5006CND, PT7C5006DNC	-	3.5	7.0	ns
				PT7C5006ANC, PT7C5006AND, PT7C5006ANE, PT7C5006ANF, PT7C5006BNC, PT7C5006BNE, PT7C5006CNE, PT7C5006DNE	-	3.5	7.0	
t_f	Output fall time	Measurement cct 3, Load cct 1, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 15pF$	$T_A = -10$ to $70^{\circ}C$	PT7C5006ANA, PT7C5006ANB, PT7C5006CNC, PT7C5006CND, PT7C5006DNC	-	3.5	7.0	ns
				PT7C5006ANC, PT7C5006AND, PT7C5006ANE, PT7C5006ANF, PT7C5006BNC, PT7C5006BNE, PT7C5006CNE, PT7C5006DNE	-	3.5	7.0	
Duty	Output duty cycle*1	Measurement cct 3, Load cct 1, $T_A = 25^{\circ}C$, $V_{DD} = 3.3V$, $C_L = 15pF$	$f = 30MHz$	PT7C5006ANA, PT7C5006ANB, PT7C5006ANC, PT7C5006CNC	40	-	60	%
			$f = 40MHz$	PT7C5006CND, PT7C5006DNC	40	-	60	
			$f = 50MHz$	PT7C5006AND, PT7C5006BNC	40	-	60	
			$f = 70MHz$	PT7C5006ANE, PT7C5006ANF, PT7C5006BNE, PT7C5006CNE, PT7C5006DNE	40	-	60	
t_{PLZ}	Output disable delay time	Measurement cct 3, Load cct 1, $T_A = 25^{\circ}C$, $V_{DD} = 5V$, $C_L \leq 15pF$			-	-	100	ns
t_{PZL}	Output enable delay time				-	-	100	ns

PT7C5006xN series

5V operation: $V_{DD}=4.5$ to $5.5V$, $T_A=-40$ to $85^{\circ}C$ unless otherwise noted.

Sym.	Parameter	Condition			Min	Typ	Max	Unit
t_r	Output rise time	Measurement cct 3, Load cct 1, $0.1V_{DD}$ to $0.9V_{DD}$	$C_L = 15pF$	PT7C5006ANA, PT7C5006ANB, PT7C5006CNC, PT7C5006CND, PT7C5006DNC	-	2.0	4.0	ns
				PT7C5006ANC, PT7C5006AND, PT7C5006BNC, PT7C5006CNE, PT7C5006DNE	-	1.5	3.0	
			$C_L = 30pF$	PT7C5006ANEDE, PT7C5006ANFDE, PT7C5006BNEDE	-	2.0	4.0	
			$C_L = 50pF$	PT7C5006ANA, PT7C5006ANB, PT7C5006CNC, PT7C5006CND, PT7C5006DNC	-	4.0	8.0	
				PT7C5006ANC, PT7C5006AND, PT7C5006BNC, PT7C5006CNE, PT7C5006DNE	-	3.5	7.0	
				PT7C5006ANE, PT7C5006ANF, PT7C5006BNE	-	3.0	6.0	
t_f	Output fall time	Measurement cct 3, Load cct 1, $0.9V_{DD}$ to $0.1V_{DD}$	$C_L = 15pF$	PT7C5006ANA, PT7C5006ANB, PT7C5006CNC, PT7C5006CND, PT7C5006DNC	-	2.0	4.0	ns
				PT7C5006ANC, PT7C5006AND, PT7C5006BNC, PT7C5006CNE, PT7C5006DNE	-	1.5	3.0	
			$C_L = 30pF$	PT7C5006ANEDE, PT7C5006ANFDE, PT7C5006BNEDE	-	2.0	4.0	
			$C_L = 50pF$	PT7C5006ANA, PT7C5006ANB, PT7C5006CNC, PT7C5006CND, PT7C5006DNC	-	4.0	8.0	
				PT7C5006ANC, PT7C5006AND, PT7C5006BNC, PT7C5006CNE, PT7C5006DNE	-	3.5	7.0	
				PT7C5006ANE, PT7C5006ANF, PT7C5006BNE	-	3.0	6.0	

-- to be continued --

 -- to be continued --

Sym.	Parameter	Condition			Min	Typ	Max	Unit
Duty	Output duty cycle	Measurement cct 3, Load cct 1, T _A =25°C, V _{DD} =5.0V	f =30MHz, C _L =50pF	PT7C5006ANA	45	-	55	%
			f =40MHz, C _L =50pF	PT7C5006ANB	45	-	55	
			f =60MHz, C _L =50pF	PT7C5006ANC	45	-	55	
			f =70MHz, C _L =50pF	PT7C5006AND, PT7C5006BNC	45	-	55	
			f =100MHz, C _L =30pF	PT7C5006ANEDE	45	-	55	
			f =100MHz, C _L =15pF	PT7C5006ANEW	45	-	55	
			f =107MHz, C _L =30pF	PT7C5006ANFDE PT7C5006BNEDE	45	-	55	
			f =107MHz, C _L =15pF	PT7C5006ANFW PT7C5006BNEW	45	-	55	
			f =50MHz, C _L =50pF	PT7C5006CNC PT7C5006DNC	45	-	55	
			f =100MHz, C _L =15pF	PT7C5006CNE PT7C5006DNE	45	-	55	
			f =60MHz, C _L =15pF	PT7C5006CNC	40	-	60	
			f =70MHz, C _L =15pF	PT7C5006CND PT7C5006DNC	40	-	60	
t _{PLZ}	Output disable delay time	Measurement cct 3, Load cct 1, T _A = 25°C, V _{DD} = 5V, C _L ≤ 15pF			-	-	100	ns
t _{PZL}	Output enable delay time				-	-	100	ns

PT7C5006×K series

5V operation: $V_{DD}=4.5$ to $5.5V$, $T_A=-40$ to $85^{\circ}C$ unless otherwise noted.

Sym.	Parameter	Condition			Min	Typ	Max	Unit
t_r	Output rise time	Measurement cct 3, Load cct 1, 0.4V to 2.4V, V_{DD} = 4.5 to 5.5V		C_L =15pF	-	2	4	ns
				C_L =50pF	-	-	7	
t_f	Output fall time	Measurement cct 3, Load cct1, 2.4V to 0.4V, V_{DD} = 4.5 to 5.5V		C_L =15pF	-	2	4	ns
				C_L =50pF	-	-	7	
Duty	Output duty cycle	Measurement cct 3, Load cct 1, T_A =25°C, V_{DD} =5.0V, C_L =15pF	f=30MHz	PT7C5006AKA	45	-	55	%
			f=40MHz	PT7C5006AKB	45	-	55	
			f=60MHz	PT7C5006AKC	40	-	60	
			f=70MHz	PT7C5006AKD PT7C5006BKC	45	-	55	
			f=50MHz	PT7C5006DKC	45	-	55	
			f=70MHz	PT7C5006CKD PT7C5006DKC	40	-	60	
t_{PLZ}	Output disable delay time	Measurement cct 3, Load cct 1, T_A = 25°C, V_{DD} = 5V, C_L ≤ 15PF			-	-	100	ns
t_{PZL}	Output enable delay time				-	-	100	ns

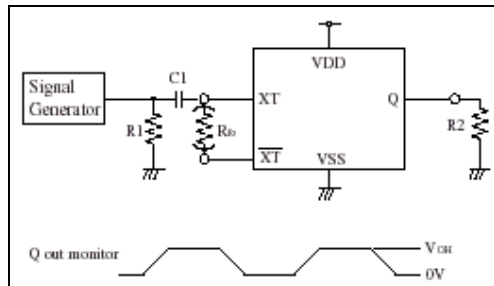
PT7C5006AH series

$V_{DD}=4.5$ to $5.5V$, $T_A=-40$ to $85^{\circ}C$ unless otherwise noted.

Sym.	Parameter	Condition			Min	Typ	Max	Unit
t_r	Output rise time	Measurement cct 3, Load cct 1, 0.1 V_{DD} to 0.9 V_{DD}		C_L =15pF	-	5.0	7.0	ns
				C_L =50pF	-	13	21	
t_f	Output fall time	Measurement cct 3, Load cct 1, 0.9 V_{DD} to 0.1 V_{DD}		C_L =15pF	-	5.0	7.0	ns
				C_L =50pF	-	13	21	
Duty	Output duty cycle*1	Measurement cct 3, Load cct 1, T_A =25°C, V_{DD} =5.0V, C_L =15pF	f=30MHz	PT7C5006AHA	45	-	55	%
			f=40MHz	PT7C5006AHB	45	-	55	
			f=50MHz	PT7C5006AHC	45	-	55	
			f=60MHz T_A =-20 to 80°C	PT7C5006AHCDE	40	-	60	
			f=60MHz T_A =-15 to 75°C	PT7C5006AHCW	40	-	60	
			f=70MHz T_A =-20 to 80°C	PT7C5006AHDDE	40	-	60	
			f=70MHz T_A =-15 to 75°C	PT7C5006AHDW	40	-	60	
t_{PLZ}	Output disable delay time	Measurement cct 3, Load cct 1, T_A = 25°C, V_{DD} = 5V, C_L ≤15PF			-	-	100	ns
t_{PZL}	Output enable delay time				-	-	100	ns

Measurement Circuit

Measurement cct 1



3.5V_{P-P}, 10MHz sine wave input signal (5V operation)

2.0V_{P-P}, 10MHz sine wave input signal (3V operation)

C1: 0.001 μ F

R1: 50 Ω

R2: 250 Ω (5006 $\times$ N $\times$ 5V operation)

275 Ω (5006 $\times$ N $\times$ 3V operation)

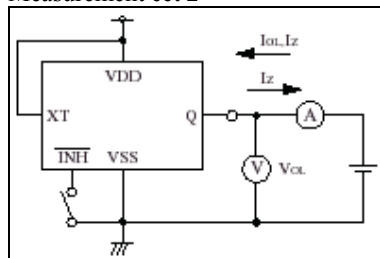
245 Ω (5006AKA, AKB, AKC, CKD, DKC)

250 Ω (5006AKD, BKC)

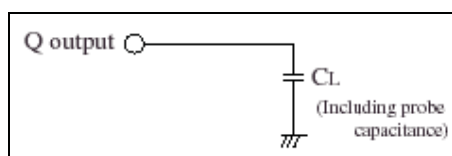
975 Ω (5006AH $\times$)

R_{fo} : 2.7k Ω (5006B $\times$ $\times$, D $\times$ $\times$)

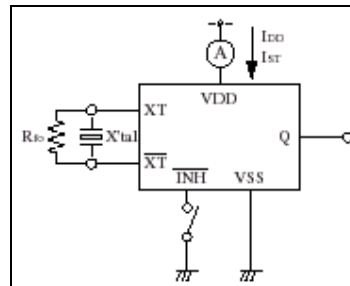
Measurement cct 2



Load cct 1

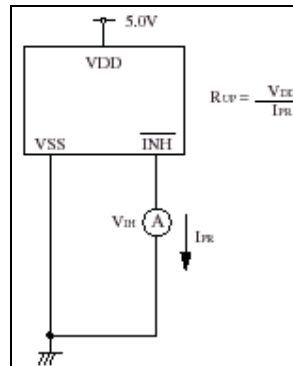


Measurement cct 3

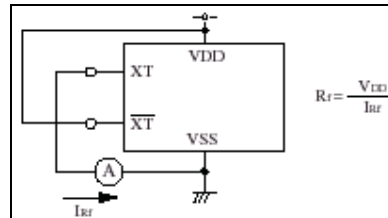


R_{fo}: 2.7k Ω (5006B $\times$ $\times$, D $\times$ $\times$)

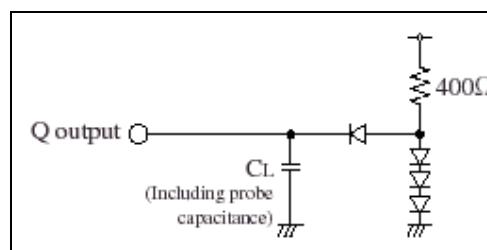
Measurement cct 4



Measurement cct 5

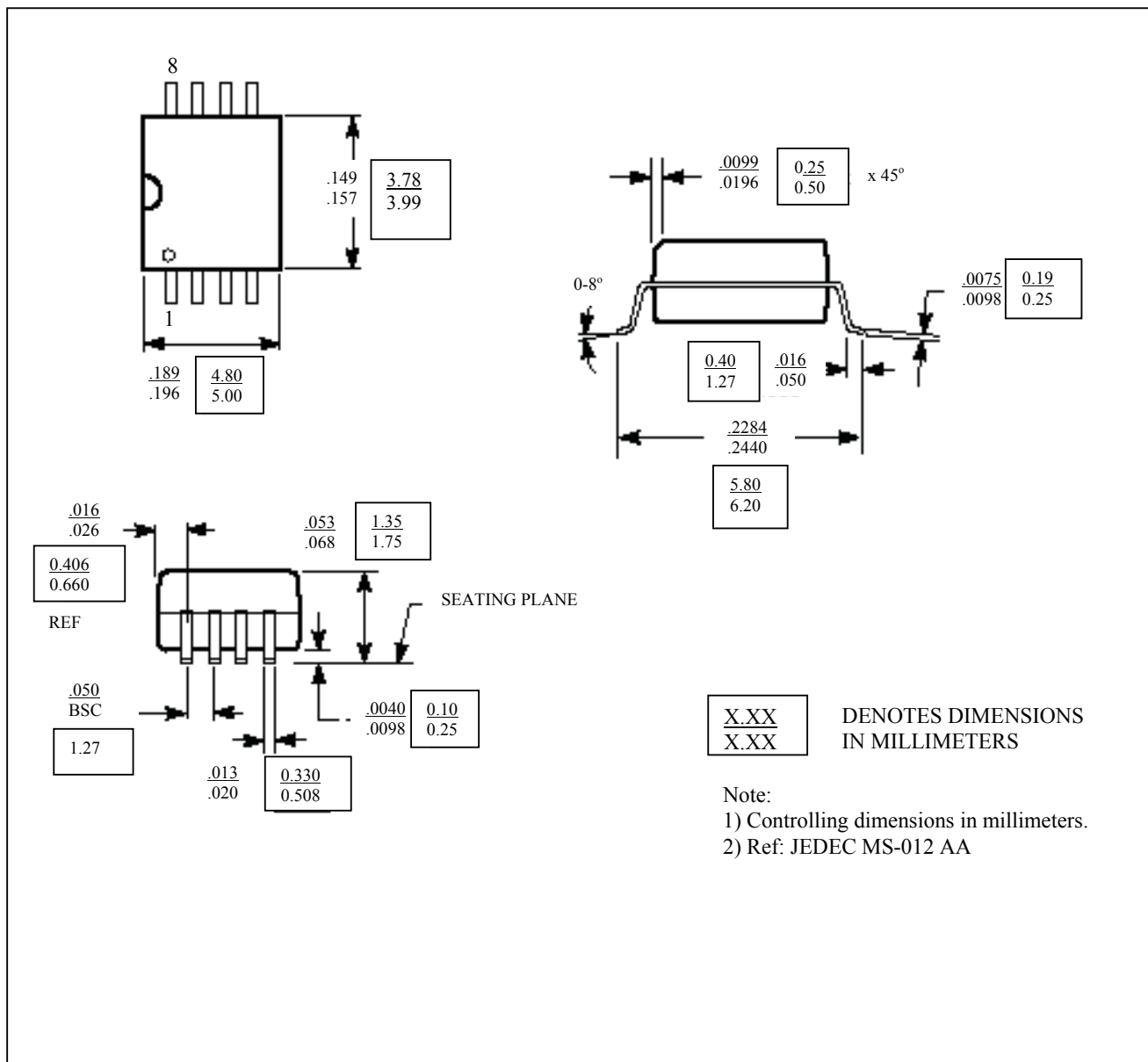


Load cct 2

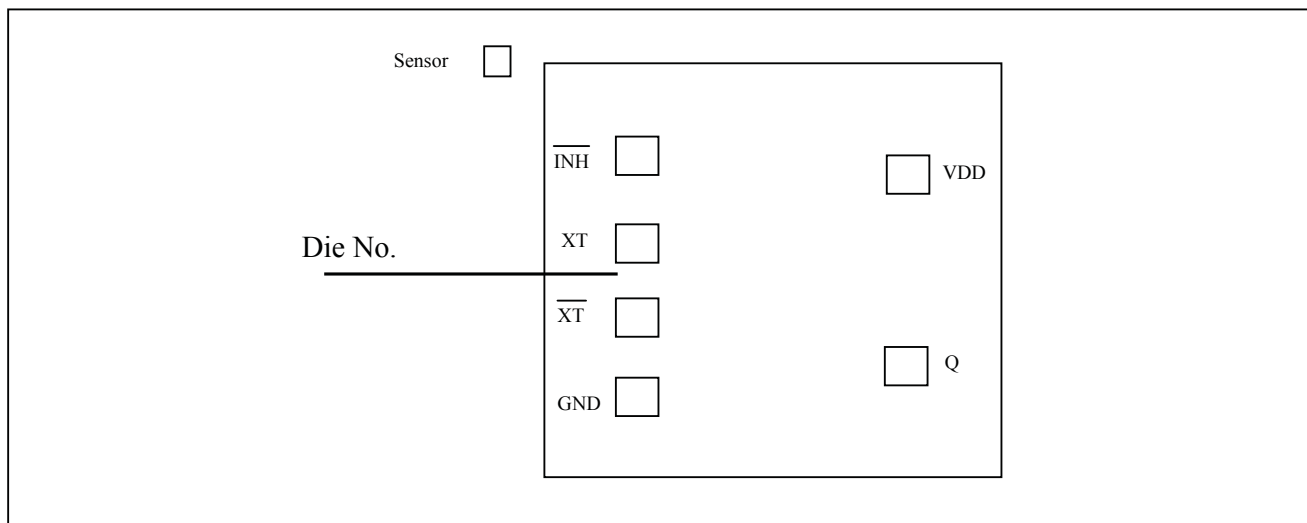


Mechanical Information

W/WE (SOIC-8)



Pad Location of PT7C5006



Pad Coordinate File					
Pad Name	X Coordinate	Y Coordinate	Pad Name	X Coordinate	Y Coordinate
sensor	-50	850.00	GND	184.20	112.80
$\overline{\text{INH}}$	184.20	687.10	VDD	815.20	542.00
XT	184.20	497.10	Q	815.20	159.00
$\overline{\text{XT}}$	184.20	302.80			
Note: Substrate is connected to GND or VDD or floating.					
Die Size: 950 μm *800 μm (Including scribe line size.)					
Die Thickness: 265 $\pm$ 25 μm					
Pad Size: 100 μm *100 μm					

Notes

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